

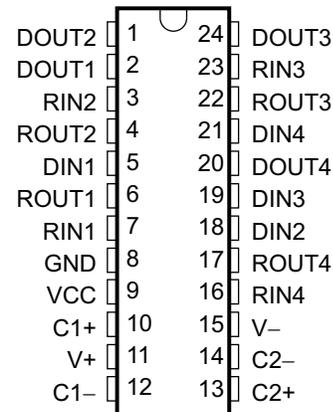
## FEATURES

- ESD Protection for RS-232 I/O Pins
  - $\pm 15$ -kV Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V  $V_{CC}$  Supply
- Four Drivers and Four Receivers
- Operates up to 120 kbit/s
- External Capacitors . . .  $4 \times 0.1 \mu\text{F}$
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

## APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

DB, DW, OR NT PACKAGE  
(TOP VIEW)



## DESCRIPTION/ORDERING INFORMATION

The TRS208 device consists of four line drivers, four line receivers, and a dual charge-pump circuit with  $\pm 15$ -kV HBM ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The devices operate at data signaling rates up to 120 kbit/s and a maximum of 30-V/ $\mu\text{s}$  driver output slew rate.

### ORDERING INFORMATION

$T_A$	PACKAGE <sup>(1)(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	PDIP – NT	Tube of 15	TRS208CNT	PREVIEW
	SOIC – DW	Tube of 25	TRS208CDW	TRS208C
		Reel of 2000	TRS208CDWR	
	SSOP – DB	Tube of 60	TRS208CDB	RU08C
Reel of 2000		TRS208CDBR		
–40°C to 85°C	PDIP – NT	Tube of 15	TRS208INT	PREVIEW
	SOIC – DW	Tube of 25	TRS208IDW	TRS208I
		Reel of 2000	TRS208IDWR	
	SSOP – DB	Tube of 60	TRS208IDB	RU08I
		Reel of 2000	TRS208IDBR	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

**FUNCTION TABLES**

**Each Driver<sup>(1)</sup>**

INPUT DIN	OUTPUT DOUT
L	H
H	L

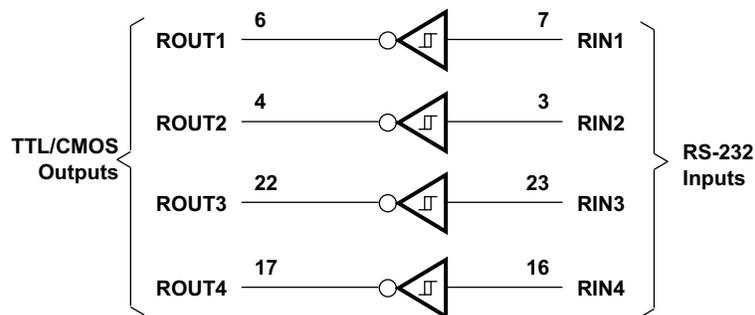
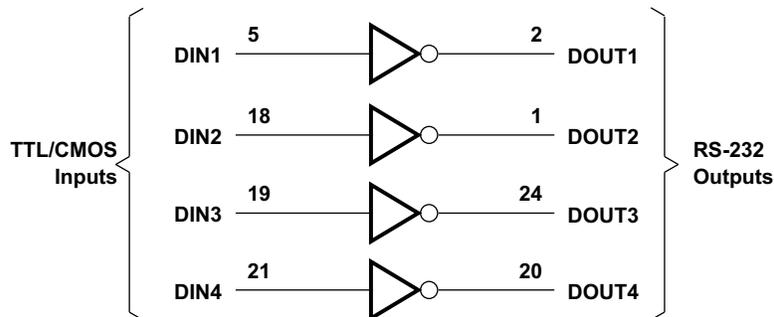
(1) H = high level, L = low level

**Each Receiver<sup>(1)</sup>**

INPUT RIN	OUTPUT ROUT
L	H
H	L
Open	H

(1) H = high level, L = low level,  
Open = input disconnected or  
connected driver off

**LOGIC DIAGRAM (POSITIVE LOGIC)**



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range <sup>(2)</sup>	-0.3	6	V
V+	Positive charge pump voltage range <sup>(2)</sup>	V <sub>CC</sub> - 0.3	14	V
V-	Negative charge pump voltage range <sup>(2)</sup>	-14	0.3	V
V+ - V-	Supply voltage difference <sup>(2)</sup>		13	V
V <sub>I</sub>	Input voltage range	Drivers	V+ + 0.3	V
		Receivers	±30	
V <sub>O</sub>	Output voltage range	Drivers	V- - 0.3	V
		Receivers	V <sub>CC</sub> + 0.3	
	Short-circuit duration	DOUT		Continuous
θ <sub>JA</sub>	Package thermal impedance	DB package <sup>(3)(4)</sup>	63	°C/W
		DW package <sup>(3)(4)</sup>	46	
		NT package <sup>(3)(5)</sup>	67	
T <sub>J</sub>	Operating virtual junction temperature		150	°C
T <sub>stg</sub>	Storage temperature range	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network GND.

(3) Maximum power dissipation is a function of T<sub>J</sub>(max), θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J</sub>(max) - T<sub>A</sub>)/θ<sub>JA</sub>. Operating at the absolute maximum T<sub>J</sub> of 150°C can affect reliability.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

(5) The package thermal impedance is calculated in accordance with JESD 51-3.

## Recommended Operating Conditions<sup>(1)</sup>

See [Figure 4](#)

		MIN	NOM	MAX	UNIT
Supply voltage		4.5	5	5.5	V
V <sub>IH</sub>	Driver high-level input voltage	DIN	2		V
V <sub>IL</sub>	Driver low-level input voltage	DIN		0.8	V
V <sub>I</sub>	Driver input voltage	DIN	0	5.5	V
	Receiver input voltage		-30	30	
T <sub>A</sub>	Operating free-air temperature	TRS208C	0	70	°C
		TRS208I	-40	85	

(1) Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 5 V ± 0.5 V.

## Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 4](#))

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I <sub>CC</sub>	Supply current	No load, V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C	11	20	mA

(1) Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 5 V ± 0.5 V.

**TRS208**  
**5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER**  
**WITH  $\pm 15$ -kV ESD PROTECTION**

SLLS810–JULY 2007

**DRIVER SECTION**

**Electrical Characteristics<sup>(1)</sup>**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 4](#))

PARAMETER		TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	DOUT at R <sub>L</sub> = 3 k $\Omega$ to GND, DIN = GND	5	9		V
V <sub>OL</sub>	Low-level output voltage	DOUT at R <sub>L</sub> = 3 k $\Omega$ to GND, DIN = V <sub>CC</sub>	–5	–9		V
I <sub>IH</sub>	High-level input current	V <sub>I</sub> = V <sub>CC</sub>		15	200	$\mu$ A
I <sub>IL</sub>	Low-level input current	V <sub>I</sub> at 0 V		–15	–200	$\mu$ A
I <sub>OS</sub> <sup>(3)</sup>	Short-circuit output current	V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 0 V		$\pm 10$	$\pm 60$	mA
r <sub>o</sub>	Output resistance	V <sub>CC</sub> , V <sub>+</sub> , and V <sub>–</sub> = 0 V, V <sub>O</sub> = $\pm 2$ V	300			$\Omega$

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

(2) All typical values are at V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C

(3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

**Switching Characteristics<sup>(1)</sup>**

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 4](#))

PARAMETER		TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
	Maximum data rate	C <sub>L</sub> = 50 pF to 1000 pF, R <sub>L</sub> = 3 k $\Omega$ to 7 k $\Omega$ , One DOUT switching, See <a href="#">Figure 1</a>	120			kbit/s
t <sub>PLH(D)</sub>	Propagation delay time, low- to high-level output	C <sub>L</sub> = 2500 pF, R <sub>L</sub> = 3 k $\Omega$ , All drivers loaded, See <a href="#">Figure 1</a>		2		$\mu$ s
t <sub>PHL(D)</sub>	Propagation delay time, high- to low-level output	C <sub>L</sub> = 2500 pF, R <sub>L</sub> = 3 k $\Omega$ , All drivers loaded, See <a href="#">Figure 1</a>		2		$\mu$ s
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	C <sub>L</sub> = 150 pF to 2500 pF, R <sub>L</sub> = 3 k $\Omega$ to 7 k $\Omega$ , See <a href="#">Figure 2</a>		300		ns
SR(tr)	Slew rate, transition region (see <a href="#">Figure 1</a> )	C <sub>L</sub> = 50 pF to 1000 pF, R <sub>L</sub> = 3 k $\Omega$ to 7 k $\Omega$ , V <sub>CC</sub> = 5 V	3	6	30	V/ $\mu$ s

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

(2) All typical values are at V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

(3) Pulse skew is defined as |t<sub>PLH</sub> – t<sub>PHL</sub>| of each channel of the same device.

**ESD Protection**

PIN	TEST CONDITIONS	TYP	UNIT
DOUT, RIN	Human-Body Model (HBM)	$\pm 15$	kV

## RECEIVER SECTION

### Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 4](#))

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = -1 mA	3.5			V
V <sub>OL</sub>	Low-level output voltage	I <sub>OL</sub> = 1.6 mA			0.4	V
V <sub>IT+</sub>	Positive-going input threshold voltage	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C		1.7	2.4	V
V <sub>IT-</sub>	Negative-going input threshold voltage	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C	0.8	1.2		V
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> - V <sub>IT-</sub> )	V <sub>CC</sub> = 5 V	0.2	0.5	1	V
r <sub>i</sub>	Input resistance	V <sub>I</sub> = $\pm 3$ V to $\pm 25$ V, V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C	3	5	7	k $\Omega$

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

### Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 3](#))

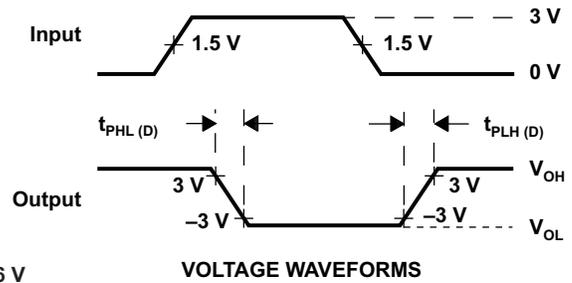
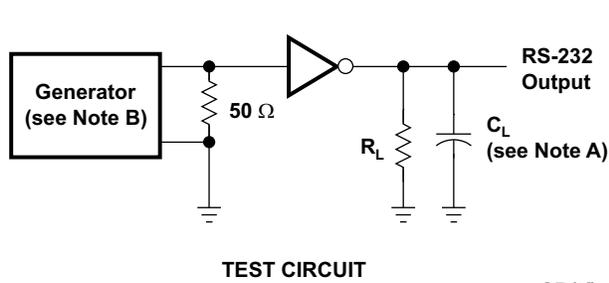
PARAMETER		TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
t <sub>PLH(R)</sub>	Propagation delay time, low- to high-level output	C <sub>L</sub> = 150 pF		0.5	10	$\mu$ s
t <sub>PHL(R)</sub>	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF		0.5	10	$\mu$ s
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>			300		ns

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

(2) All typical values are at V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

(3) Pulse skew is defined as |t<sub>PLH</sub> - t<sub>PHL</sub>| of each channel of the same device.

PARAMETER MEASUREMENT INFORMATION

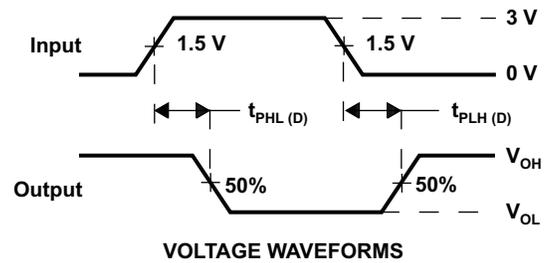
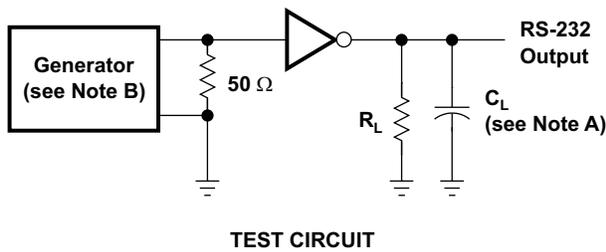


$$SR(tf) = \frac{6\text{ V}}{t_{PHL(D)} \text{ or } t_{PLH(D)}}$$

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, Z<sub>O</sub> = 50 Ω, 50% duty cycle, t<sub>r</sub> ≤ 10 ns, t<sub>f</sub> ≤ 10 ns.

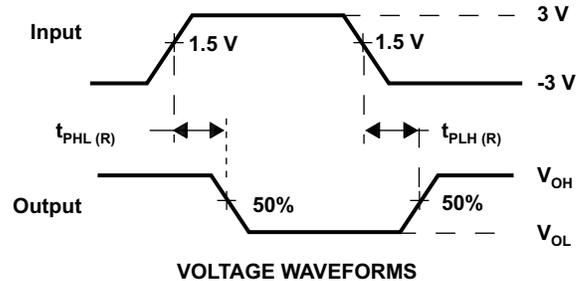
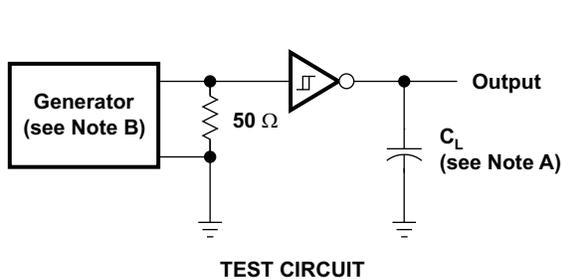
Figure 1. Driver Slew Rate



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, Z<sub>O</sub> = 50 Ω, 50% duty cycle, t<sub>r</sub> ≤ 10 ns, t<sub>f</sub> ≤ 10 ns.

Figure 2. Driver Pulse Skew

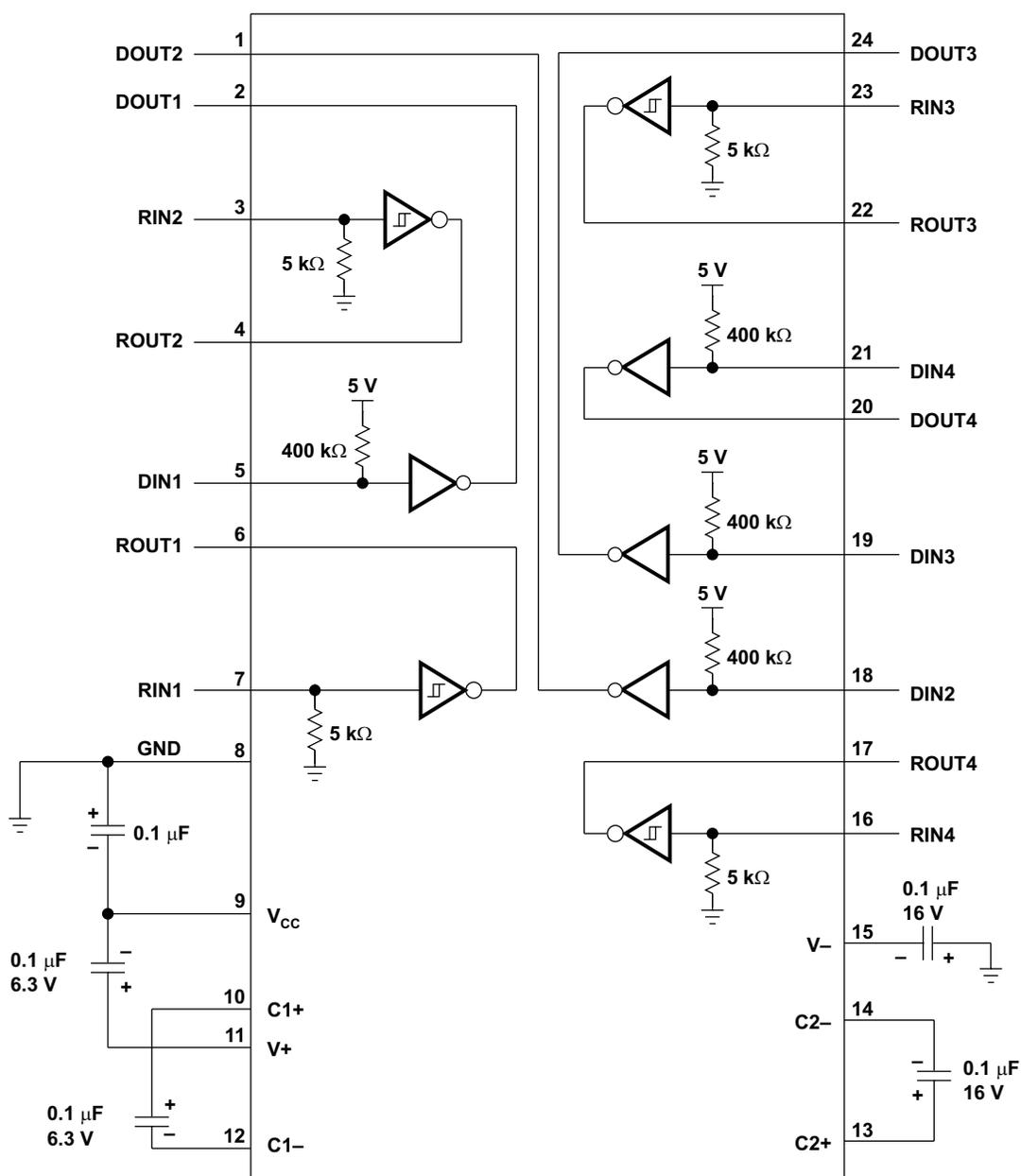


NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: Z<sub>O</sub> = 50 Ω, 50% duty cycle, t<sub>r</sub> ≤ 10 ns, t<sub>f</sub> ≤ 10 ns.

Figure 3. Receiver Propagation Delay Times

APPLICATION INFORMATION



- NOTES: A. Resistor values shown are nominal.  
 B. Non-polarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 4. Typical Operating Circuit and Capacitor Values

## APPLICATION INFORMATION (continued)

### Capacitor Selection

The capacitor type used for C1–C4 is not critical for proper operation. The TRS208 requires 0.1- $\mu\text{F}$  capacitors, although capacitors up to 10  $\mu\text{F}$  can be used without harm. Ceramic dielectrics are suggested for the 0.1- $\mu\text{F}$  capacitors. When using the minimum recommended capacitor values, ensure that the capacitance value does not degrade excessively as the operating temperature varies. If in doubt, use capacitors with a larger (e.g., 2 $\times$ ) nominal value. The capacitors' effective series resistance (ESR), which usually rises at low temperatures, influences the amount of ripple on V+ and V–.

Use larger capacitors (up to 10  $\mu\text{F}$ ) to reduce the output impedance at V+ and V–.

Bypass  $V_{\text{CC}}$  to ground with at least 0.1  $\mu\text{F}$ . In applications sensitive to power-supply noise generated by the charge pumps, decouple  $V_{\text{CC}}$  to ground with a capacitor the same size as (or larger than) the charge-pump capacitors (C1–C4).

### Electrostatic Discharge (ESD) Protection

TI TRS208 devices have standard ESD protection structures incorporated on the pins to protect against electrostatic discharges encountered during assembly and handling. In addition, the RS-232 bus pins (driver outputs and receiver inputs) of these devices have an extra level of ESD protection. Advanced ESD structures were designed to successfully protect these bus pins against ESD discharge of  $\pm 15$  kV when powered down.

### ESD Test Conditions

ESD testing is stringently performed by TI, based on various conditions and procedures. Please contact TI for a reliability report that documents test setup, methodology, and results.

### Human-Body Model (HBM)

The HBM of ESD testing is shown in Figure 5, while Figure 6 shows the current waveform that is generated during a discharge into a low impedance. The model consists of a 100-pF capacitor, charged to the ESD voltage of concern and subsequently discharged into the DUT through a 1.5-k $\Omega$  resistor.

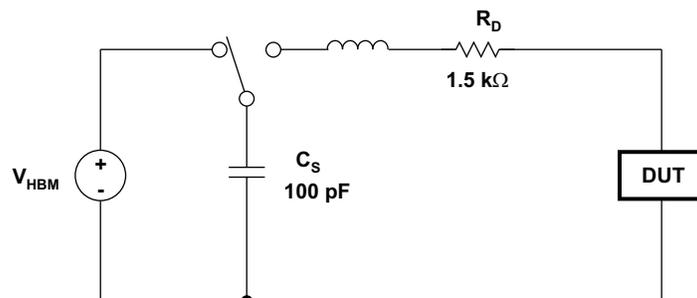
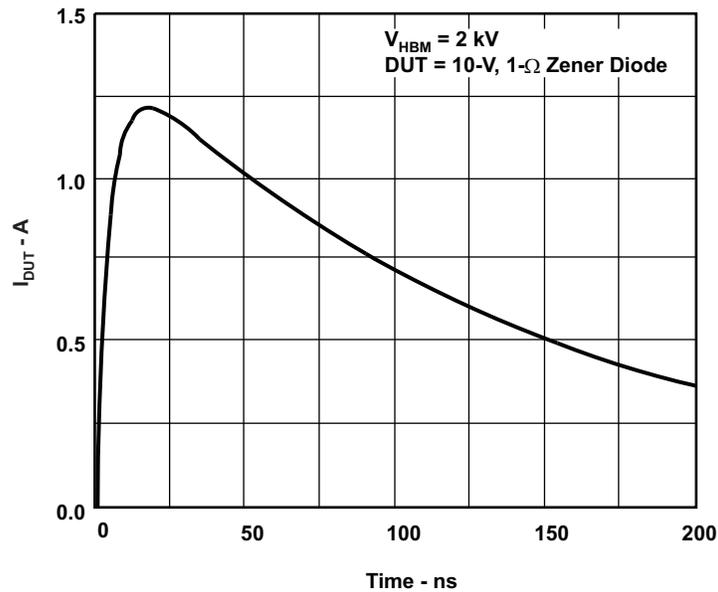


Figure 5. HBM ESD Test Circuit

**APPLICATION INFORMATION (continued)**



**Figure 6. Typical HBM Current Waveform**

**Machine Model (MM)**

The MM ESD test applies to all pins using a 200-pF capacitor with no discharge resistance. The purpose of the MM test is to simulate possible ESD conditions that can occur during the handling and assembly processes of manufacturing. In this case, ESD protection is required for all pins, not just RS-232 pins. However, after PC board assembly, the MM test no longer is as pertinent to the RS-232 pins.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TRS208CDB	LIFEBUY	SSOP	DB	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	RU08C	
TRS208CDBR	LIFEBUY	SSOP	DB	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	RU08C	
TRS208CDWR	LIFEBUY	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS208C	
TRS208IDB	LIFEBUY	SSOP	DB	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU08I	
TRS208IDBR	ACTIVE	SSOP	DB	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU08I	Samples
TRS208IDWR	LIFEBUY	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS208I	

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

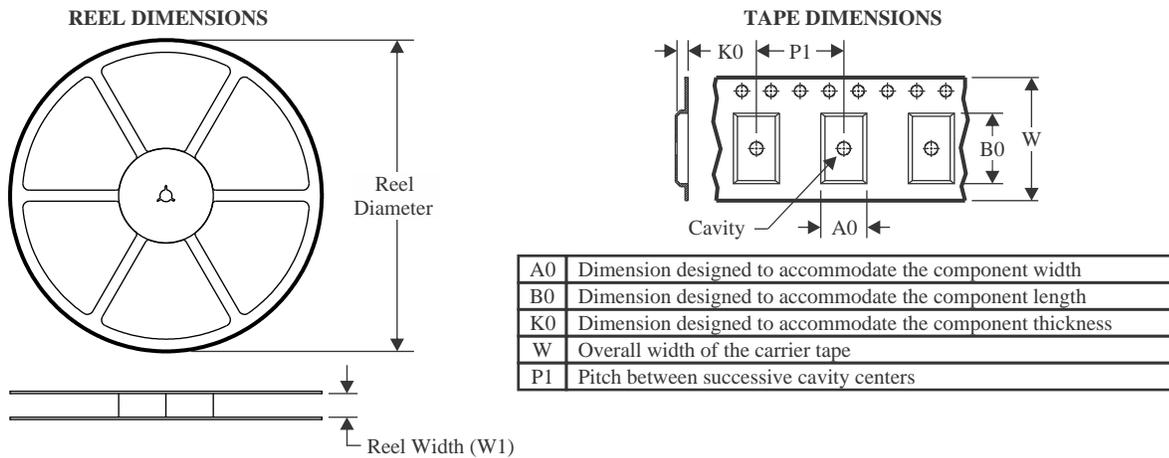
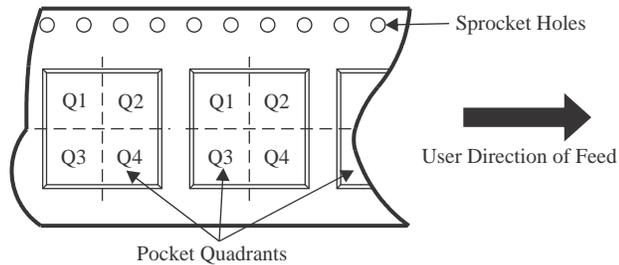
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

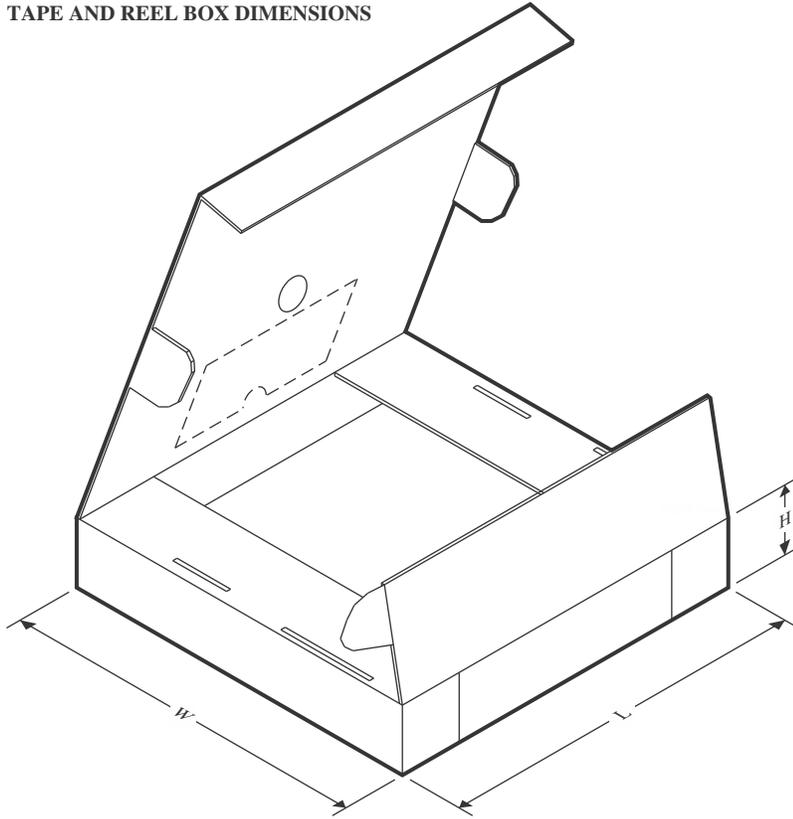
continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


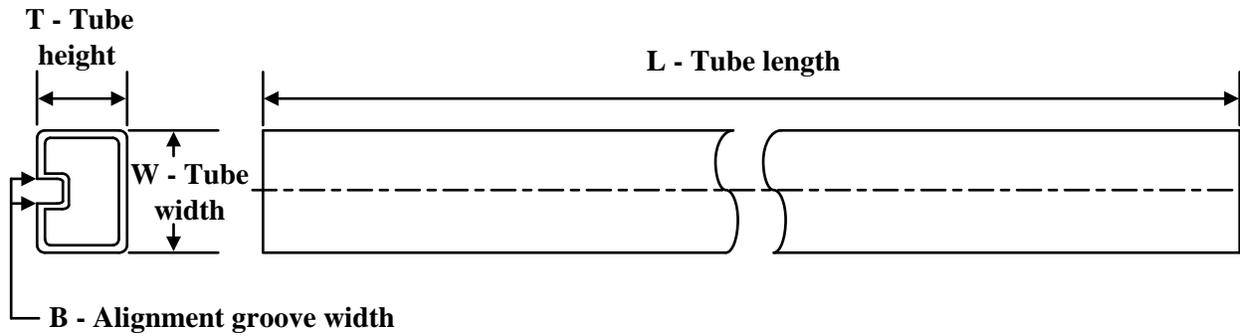
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS208CDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
TRS208CDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
TRS208IDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
TRS208IDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS208CDBR	SSOP	DB	24	2000	356.0	356.0	35.0
TRS208CDWR	SOIC	DW	24	2000	350.0	350.0	43.0
TRS208IDBR	SSOP	DB	24	2000	356.0	356.0	35.0
TRS208IDWR	SOIC	DW	24	2000	350.0	350.0	43.0

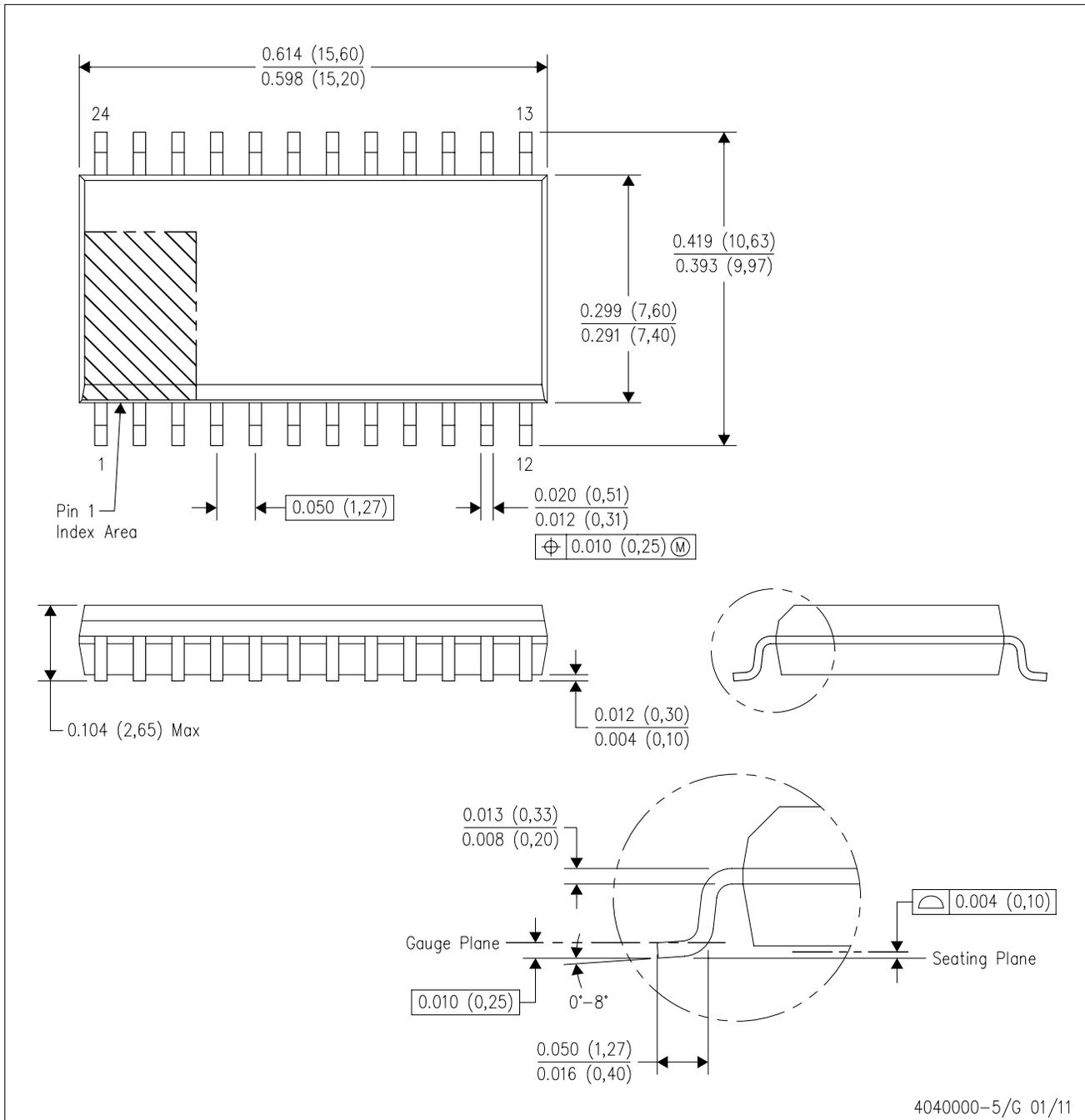
**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TRS208CDB	DB	SSOP	24	60	530	10.5	4000	4.1
TRS208IDB	DB	SSOP	24	60	530	10.5	4000	4.1

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE

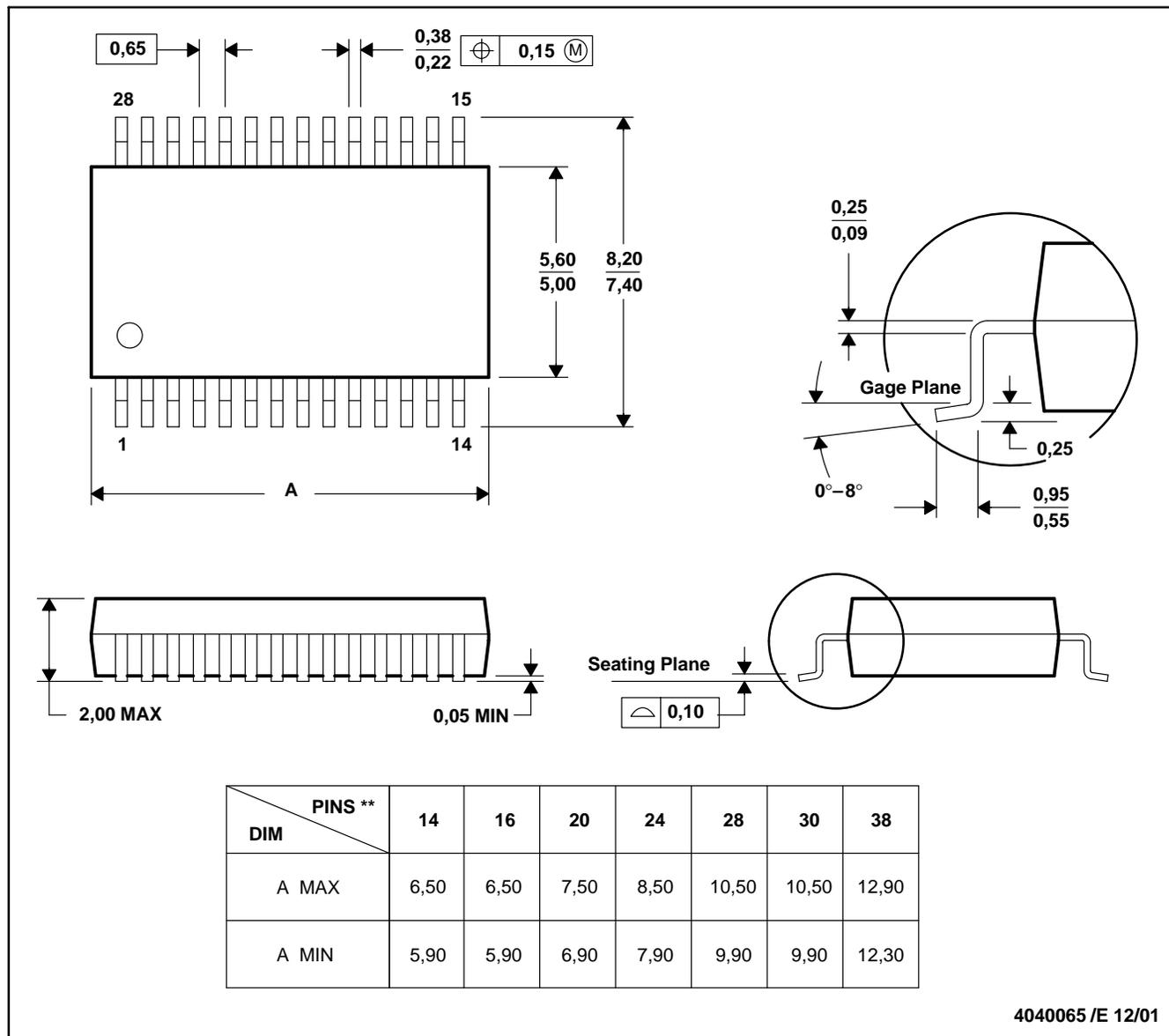


- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AD.

DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-150

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